



DMP21D0UFB4

### **Product Summary**

BV <sub>DSS</sub>	Rds(on) max	<b>I</b> d мах @ Т <sub>А</sub> = +25°С
-20V	495mΩ @ V <sub>GS</sub> = -4.5V	-0.77A
	690mΩ @ V <sub>GS</sub> = -2.5V	-0.67A
	960mΩ @ V <sub>GS</sub> = -1.8V	-0.57A

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$ , yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Portable Electronics

#### 20V P-CHANNEL ENHANCEMENT MODE MOSFET

## Features and Benefits

- Footprint of just 0.6mm<sup>2</sup> 13 Times Smaller than SOT23
- 0.4mm Profile Ideal for Low Profile Applications
- Low Gate Threshold Voltage
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

#### **Mechanical Data**

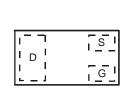
- Case: X2-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @
- Weight: 0.001 grams (Approximate)

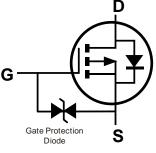




X2-DFN1006-3

Bottom View





Top View Internal Schematic

Equivalent Circuit

# Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Tape Pitch (mm)	Quantity per Reel
DMP21D0UFB4-7R	NO	7	8	4	3,000
DMP21D0UFB4-7B	NO	7	8	2	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



# **Marking Information**

DMP21D0UFB4-7R	Top View Bar Denotes Gate and Source Side	NO = Part Marking Code	
DMP21D0UFB4-7B	Top View Bar Denotes Gate and Source Side	NO = Part Marking Code	



# Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit	
Drain-Source Voltage		Vdss	-20	V		
Gate-Source Voltage		Vgss	±8	V		
Continuous Drain Current	Oterate	T <sub>A</sub> = +25°C (Note 5)	١D	-0.77		
	Steady State	T <sub>A</sub> = +85°C (Note 5)		-0.55	A	
	State	T <sub>A</sub> = +25°C (Note 6)		-1.17		
Pulsed Drain Current (Note 7)		IDM	-5.0	A		

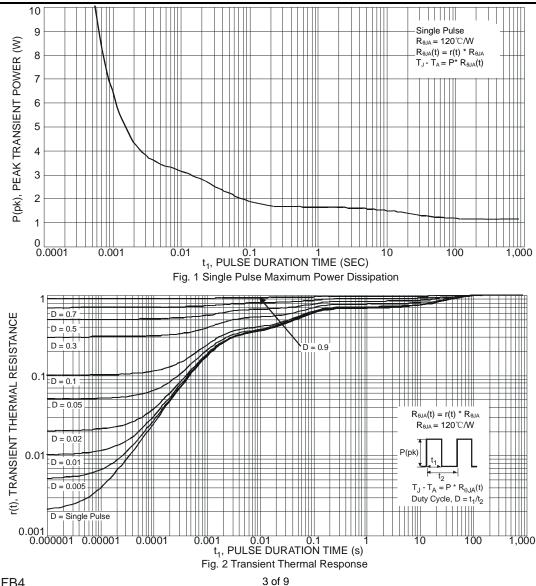
#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	0.43	W
Power Dissipation (Note 6)	PD	0.99	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	293	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	126	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate. Notes:

7. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.

#### Thermal Characteristics



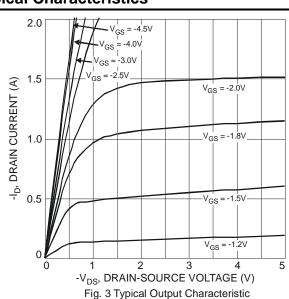


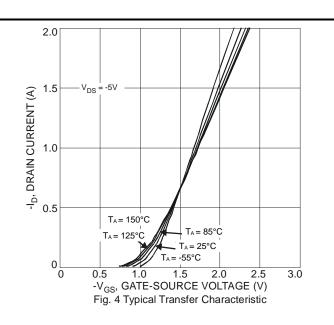
## Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BVDSS	-20	_		V	$V_{GS} = 0V, I_D = -250 \mu A$
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	IDSS		—	-1	μA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_	_	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.5	-0.7	-1.0	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$
				495		$V_{GS} = -4.5V, I_D = -400mA$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	—	—	690	mΩ	$V_{GS} = -2.5V, I_D = -300mA$
	-(- )			960		$V_{GS} = -1.8V, I_{D} = -100mA$
Forward Transfer Admittance	YFS	50	—		ms	$V_{DS} = -3V, I_{D} = -300 \text{mA}$
Diode Forward Voltage	Vsd		—	-1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -300mA
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss		76.5	_	pF	
Output Capacitance	Coss	_	13.7		pF	V <sub>DS</sub> = -10V, V <sub>GS</sub> = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss		10.7		pF	1 - 1.00012
Gate Resistance	Rg		195	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Qg	_	1.5	_	nC	V <sub>GS</sub> = -8V, V <sub>DS</sub> = -15V, I <sub>D</sub> = -1A
Total Gate Charge	Qg	_	1.0	_	nC	
Gate-Source Charge	Qgs	_	0.2	_	nC	VGS = -4.5V, VDS = -15V, ID = -1A
Gate-Drain Charge	Qgd	_	0.3	_	nC	ID = -IA
Turn-On Delay Time	tD(ON)		7.1		ns	
Turn-On Rise Time	tR		8.0	—	ns	$V_{DS} = -10V, -I_{D} = 1A$
Turn-Off Delay Time	tD(OFF)	_	31.7		ns	$V_{GS} = -4.5V, R_{g} = 6\Omega$
Turn-Off Fall Time	tF	_	18.5		ns	

 Notes:
 8. Short duration pulse test used to minimize self-heating effect.

 9. Guaranteed by design. Not subject to product testing.

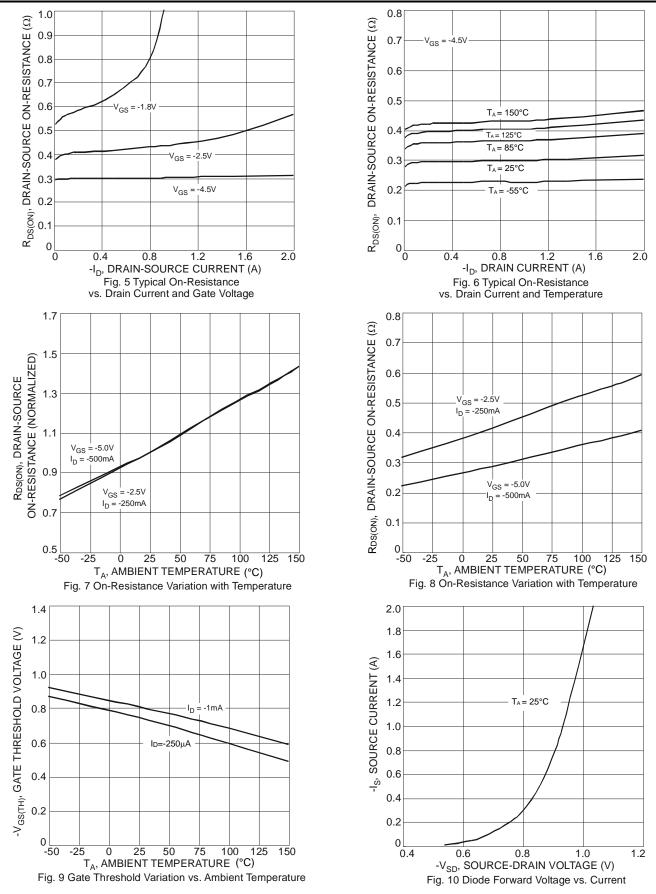




# **Typical Characteristics**



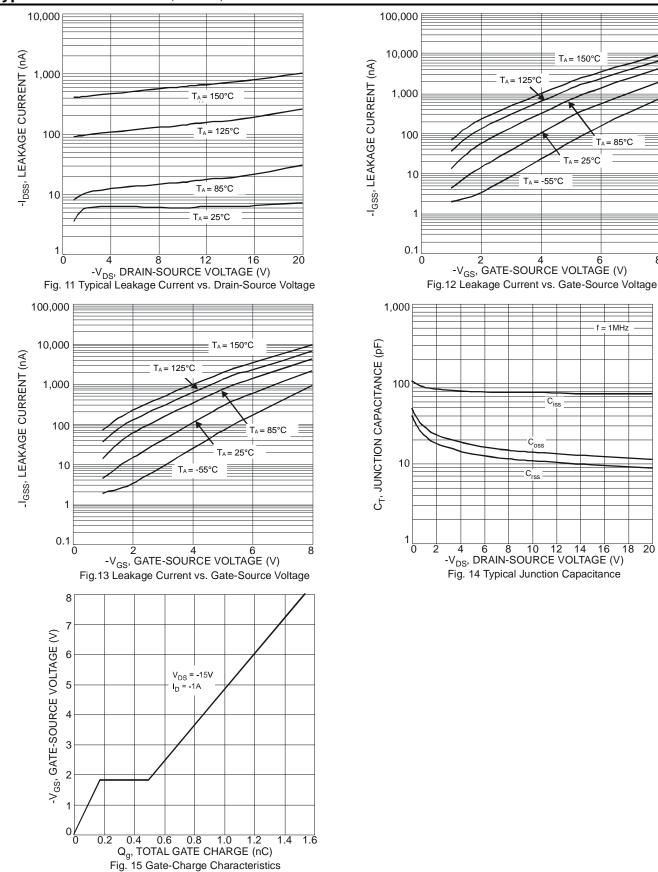
# Typical Characteristics (continued)





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## Typical Characteristics (continued)

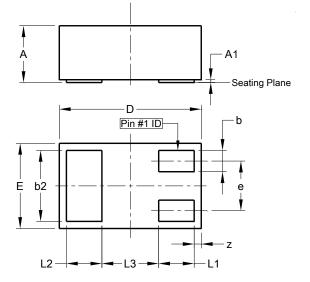




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

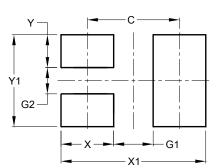
#### X2-DFN1006-3



X2-DFN1006-3						
Dim	Dim Min Max Typ					
Α		0.40				
A1	0.00	0.05	0.03			
Ь	0.10	0.20	0.15			
b2	0.45	0.55	0.50			
D	0.95	1.05	1.00			
Ε	0.55	0.65	0.60			
е			0.35			
L1	0.20	0.30	0.25			
L2	0.20	0.30	0.25			
L3			0.40			
Z	0.02	0.08	0.05			
All D	imens	ions iı	n mm			

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



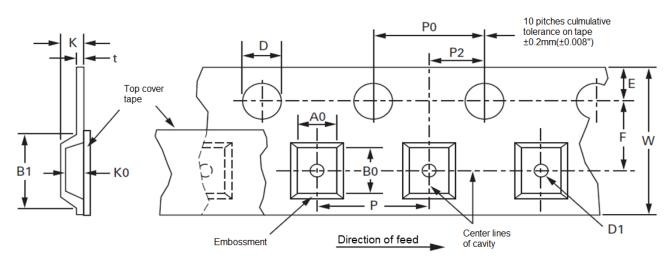
#### X2-DFN1006-3

Dimensions	Value (in mm)
С	0.70
G1	0.30
G2	0.20
Х	0.40
X1	1.10
Y	0.25
Y1	0.70



# **Embossed Carrier Tape Specifications**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Tape Width (W)	Dimension	Value (mm)	Dimension	Value (mm)	Dimension	Value (mm)
	B1	4.5 max.	F	3.5±0.05	P2	2.0±0.05
	D	1.5+0.10 -0.0	к	2.4 max.	t	0.40 max.
8mm D1	D1	0.35 min.	Р	4.0±0.10 2.0±0.05(-7B)	W	8±0.30
	E	1.75±0.10	P0	4.0±0.10		
A0 B0 K0 Determined by component size. The clearance between the component and the to the rotational and lateral movement requirement provided in figures in the "Ma Movement in Tape Pocket" section.						



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